

Avalanche Diode

DL143-800



Average forward current		I_{FAV}	800 A	
Repetitive peak reverse voltage		V_{RRM}	2800 - 3400 V	
V_{RRM} , V	2800	3000	3200	3400
Voltage class	28	30	32	34
T_j , °C	-60 ... +160			

MAXIMUM RATINGS

Parameters	Symbols	Maximum Limits	Unit
Repetitive peak reverse voltage, $T_j = -60\text{ °C} \dots +160\text{ °C}$	V_{RRM}	2800 - 3400	V
Non-repetitive peak reverse voltage, $T_j = -60\text{ °C} \dots +160\text{ °C}$	V_{RSM}	3200 - 3800	
Repetitive reverse current, $T_j = 160\text{ °C}$, $V_R = V_{RRM}$	I_{RRM}	50	mA
Average forward current, $T_C = 110\text{ °C}$, $f = 50\text{ Hz}$	$I_{F(AV)}$	880	A
RMS forward current, $T_C = 110\text{ °C}$, $f = 50\text{ Hz}$	I_{FRMS}	1380	
Non repetitive peak surge current, $T_j = 160\text{ °C}$, $V_R = 0$, $t_p = 10\text{ ms}$	I_{FSM}	11	kA
I^2t -value	I^2t	$10^3 \cdot 605$	A ² s
Junction temperature range	T_j	-60 ... +160	°C
Storage temperature range	T_{stg}	-60 ... +50	

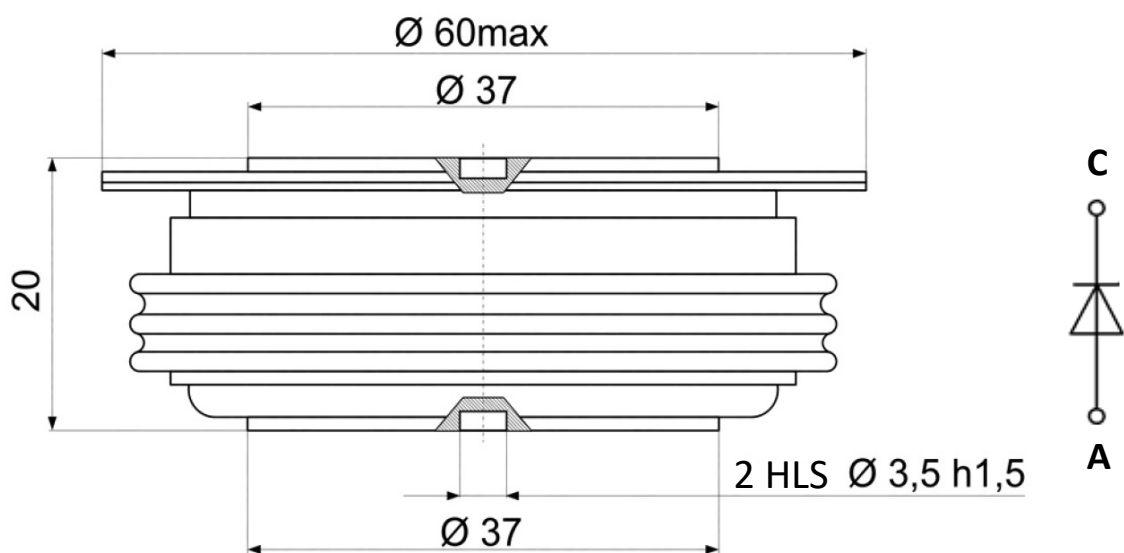
ELECTRICAL CHARACTERISTICS

Parameters	Symbols	Value			Unit
		min	typ	max	
Maximum forward voltage, $T_j = 25\text{ °C}$, $I_F = 2500\text{ A}$	V_{FM}	-	-	1.85	V
Threshold voltage, $T_j = 160\text{ °C}$, $I_F = 1250 - 3800\text{ A}$	V_{TO}	-	-	1.00	V
Forward slope resistance, $T_j = 160\text{ °C}$, $I_F = 1250 - 3800\text{ A}$	r_T	-	-	0.50	mΩ
Maximum avalanche power dissipation, $T_j = 160\text{ °C}$, $t_p = 100\text{ μs}$	P_{RSM}	-	-	16.0	μC

THERMAL PARAMETERS					
Thermal resistance junction to case double side cooling anode side cooling cathode side cooling	$R_{th(j-c)}$	-	-	0.027 0.054 0.054	°C/W
Thermal resistance case to heatsink double side cooling single side cooling	$R_{th(c-h)}$	-	-	0.010 0.020	
MECHANICAL PARAMETERS					
Weight	w	-	240	-	g
Clamping force	F	13.5	-	16.5	kN
Maximum permissible continuous acceleration	a	-	-	100	m/s ²

DIMENSIONS

Housing type: PD42, D.C2



C – cathode
A – anode

All dimensions are in millimeters